

TMR9003

Ultra High Sensitivity, Ultra Low Noise TMR linear sensor

General Description

The TMR9003 linear sensor utilizes a unique push-pull Wheatstone bridge composed of four TMR sensor elements. The unique bridge design provides a high sensitivity differential output that is linearly proportional to a magnetic field applied parallel to the surface of the sensor package, and it provides superior temperature compensation of the output. The TMR9003 is assembled in a $6mm \times 5mm \times 1.5mm$ SOP8 package.

Features and Benefits

- Tunneling Magnetoresistance (TMR) Technology
- High Sensitivity(~30mV/V/Oe)
- Ultra-low Noise Spectral Density(750pT/√Hz@1Hz)
- Very-low Power Consumption
- Excellent Thermal Stability
- Low Hysteresis
- Compatible with Wide Range of Supply Voltages
- No need for set/reset calibration

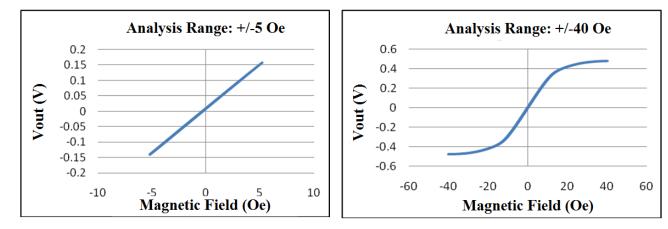
Applications

- Weak Magnetic Field Sensing
- Current Sensors
- Position and Displacement Sensing
- Biomedical Sensing
- Magnetic Communication



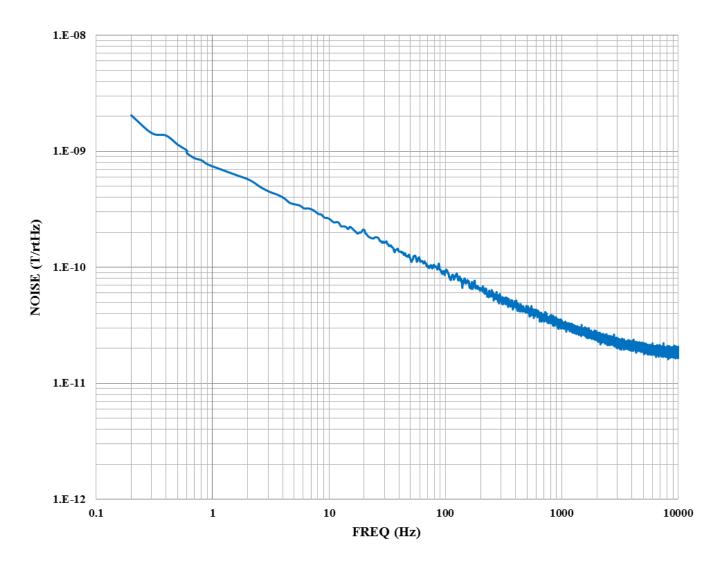
Transfer Curve

The following figure shows the response of the TMR9003 to an applied magnetic field in the range of ± 5 Oe and ± 40 Oe when the TMR9003 is biased at 1 V. The following specifications are calculated over an analysis range of ± 5 Oe.



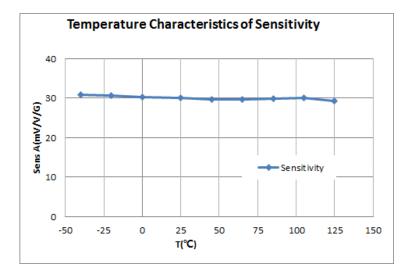
Sensor Noise

The following figure illustrates the Power SpectralDensity (PSD) of the TMR9003 self noise (*N*i). The 1/*f*noise is approximately750 pT/ $\sqrt{\text{Hz}}$ @ 1Hz, and the white noise is approximately 20pT/ $\sqrt{\text{Hz}}$ @ 10kHz.



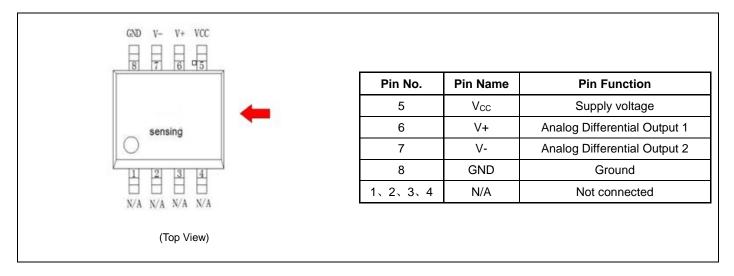
Sensitivity temperature characteristic curve.

The figure below shows the temperature characteristic curve of the TMR9002 sensor (test temperature range: -40, c ~125)



Pin Configuration

(Arrow indicates direction of applied field that generates a positive output voltage.)



Absolute Maximum Ratings

Parameter	Symbol	Limit	Unit	
Supply Voltage	V _{CC}	3	V	
Reverse Supply Voltage	V _{RCC}	3	V	
Max Exposed Field	H _E	4000	Oe ⁽¹⁾	
ESD Voltage	V _{ESD}	4000	V	
Operating Temperature	T _A	-40~125	°C	
Storage Temperature	T _{stg}	-50 ~150	C°	

Specification (V_{CC}=1.0V, T_A=25°C)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	V _{cc}	Normal Operating		1	3	V
Supply Current	I _{CC}	Output Open		20 ⁽²⁾		μA
Resistance	R			50		kOhm
Sensitivity	SEN	Fit ±50e		30		mV/V/Oe
Saturation Field	H _{sat}			±15		Oe
Non -Linearity	NONL	Fit ±50e		0.5		%FS
Offset Voltage	V _{offset}			10		mV/V
Hysteresis	Hys	Fit ±50e		0.1		Oe
Resistance temperature coefficient	TCR	-40 ⁰c ~125 ⁰c		-487		PPM/⁰c
Sensitivity temperature coefficient.	TCS	-40 ºc ~125 ºc		-495		PPM/ºc
Self Noise	Ni	@1Hz		750		pT/√Hz

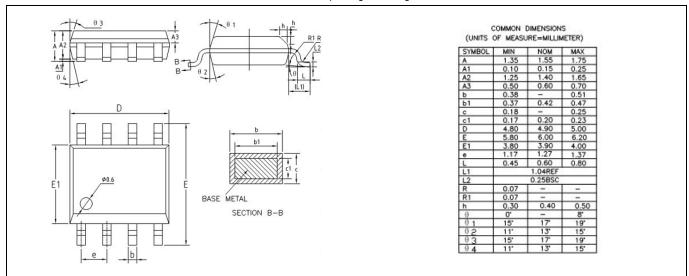
Note:

(1) 1 Oe (Oersted) = 1 Gauss in air = 0.1 millitesla = 79.8 A/m.

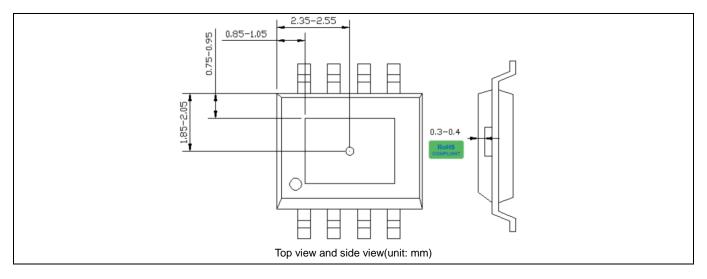
(2) ICC= VCC/R, Iccwill vary under different R in practice and it can be customized accordingly.

Package Information

SOP8 package drawing



TMR Sensor Position







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